50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

14 September 2018

Product data sheet

### 1. General description

NPN/NPN Resistor-Equipped double Transistors (RET) in a leadless ultra small DFN1412-6 (SOT1268) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- · Low package height of 0.5 mm
- AEC-Q101 qualified

### 3. Applications

- · Digital applications
- Cost-saving alternative to BC847/BC857 series in digital applications
- · Control of IC inputs
- Switching loads

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or	•	,				
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	3.7	4.7	5.7	

<sup>[1]</sup> See section "Test information" for resistor calculation and test conditions.



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# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	7 6	
3	O2	output (collector) TR2	5	R1 R2
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2	3 8 4	R2 R1
6	01	output (collector) TR1		
7	O1	output (collector) TR1	Transparent top view	
8	O2	output (collector) TR2	DFN1412-6 (SOT1268)	GND1 I1 O2 aaa-019894

# 6. Ordering information

**Table 3. Ordering information** 

Type number Package					
	Name	Description	Version		
PRMH9		plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body: 1.4 mm x 1.2 mm x 0.47 mm	SOT1268		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PRMH9	B8

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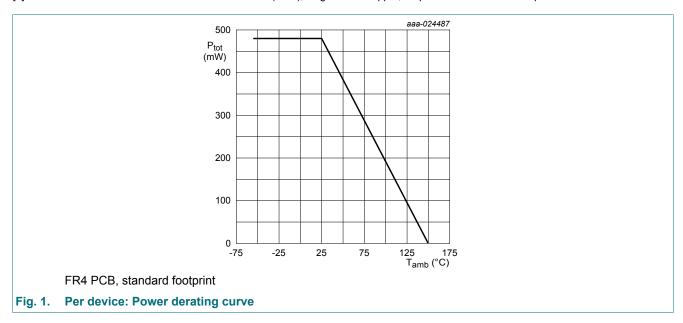
# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		'	'		
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	6	V
VI	input voltage	positive		-	40	V
		negative		-	-6	V
Io	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	325	mW
Per device			,	'		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device	Per device						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

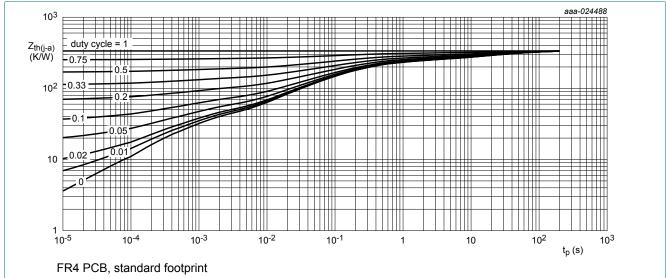


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

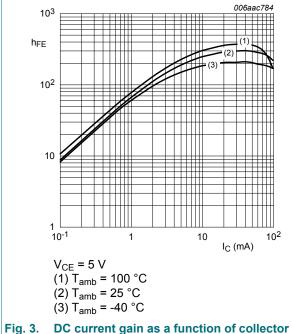
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### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	1	μΑ
	current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 150 °C		-	-	5	μA
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	150	μA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C		100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	100	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 μA; T <sub>amb</sub> = 25 °C		-	0.7	0.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 1 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		1.4	0.8	-	V
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	3.7	4.7	5.7	
C <sub>C</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	230	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



3. DC current gain as a function of collector current; typical values

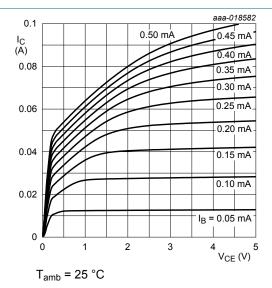
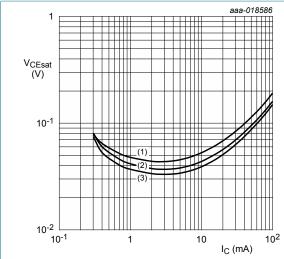


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

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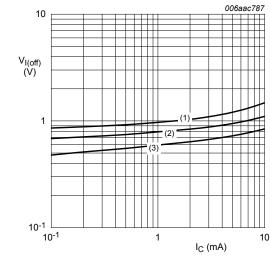


$$I_{\rm C}/I_{\rm B} = 20$$

$$(1) T_{amb} = 100 ° ($$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

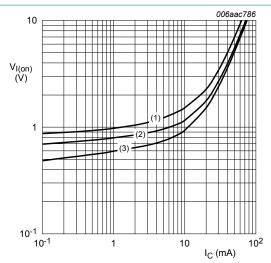
Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

(3) 
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. Off-state input voltage as a function of collector current; typical values

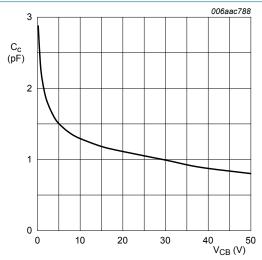


$$V_{CF} = 0.3 \text{ V}$$

$$(1) T_{amb} = -40 ° ($$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 6. On-state input voltage as a function of collector current; typical values

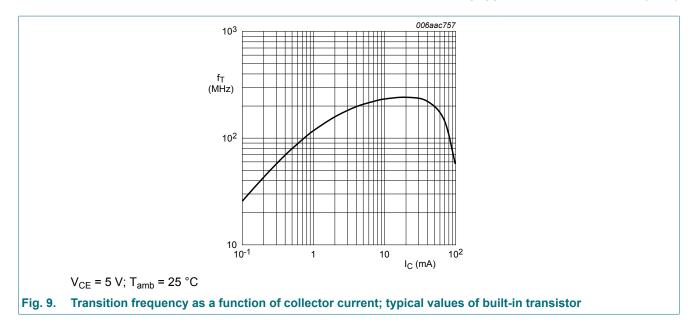


 $f = 1 MHz; T_{amb} = 25 °C$ 

Fig. 8. Collector capacitance as a function of collectorbase voltage; typical values

<sup>(1)</sup>  $T_{amb} = -40 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ 

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### 11. Test information

#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

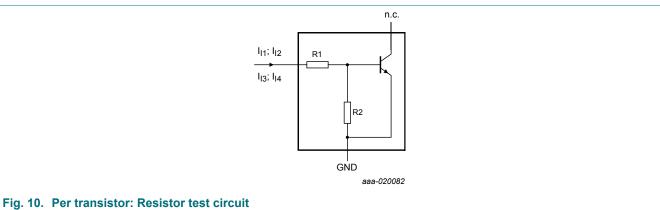
#### **Resistor calculation**

Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$



#### **Resistor test conditions**

**Table 8. Resistor test conditions** 

R1 (kΩ)	R2 (kΩ)	Test conditions			
		I <sub>I1</sub>	l <sub>12</sub>	I <sub>13</sub>	I <sub>14</sub>
10	47	90 μΑ	140 μΑ	-55 μΑ	-105 μA

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#### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

# 12. Package outline

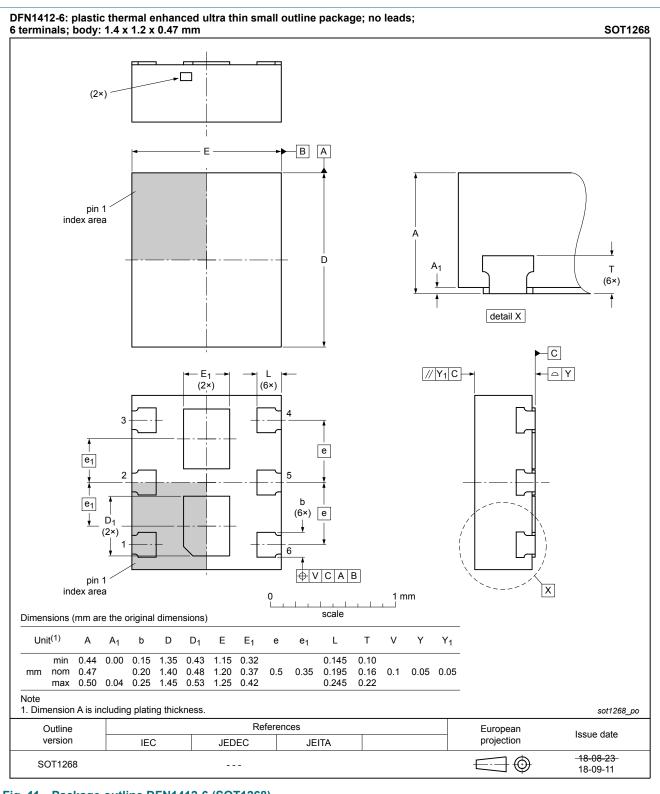
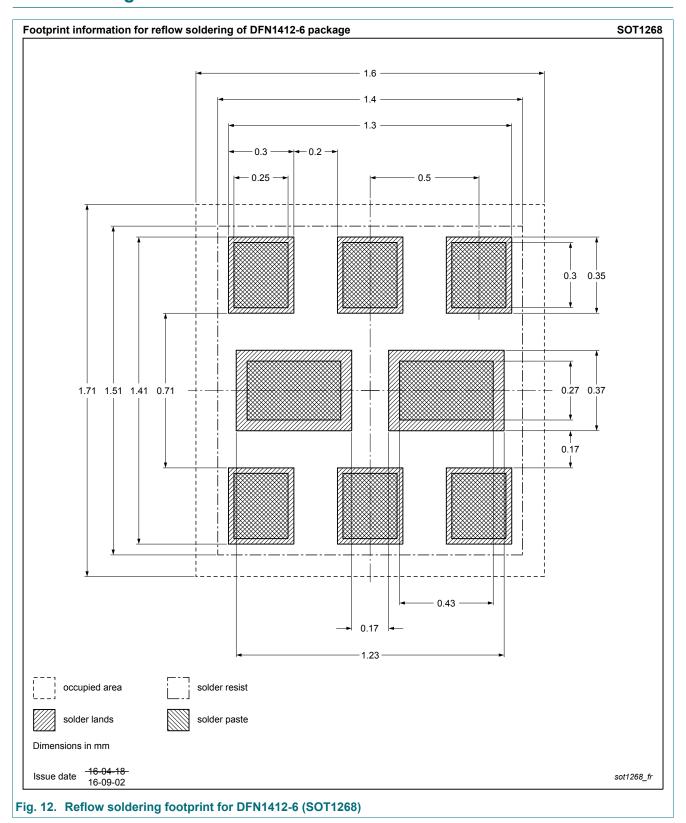


Fig. 11. Package outline DFN1412-6 (SOT1268)

### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

# 13. Soldering



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### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

# 14. Revision history

#### Table 9. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PRMH9 v.2	20180914	Product data sheet	-	PRMH9 v.1			
Modifications:	Package outline draw	Package outline drawing updated: Unit T added					
PRMH9 v.1	20170613	Product data sheet	-	-			

#### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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